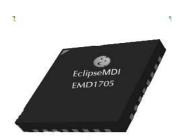
EMD1705QFN4 Driver Amplifier

DC-20 GHz GaAs PHEMT MMIC Driver Amplifier



Technical Characteristics



Product Features

15.0 dB Gain @ 10 GHz

+24.0 dBm P1dB Output Power @ 10 GHz

+8V @ 190 mA typical supply voltage

Low cost QFN 4mm leadless RoHS compliant/hermetically Sealed

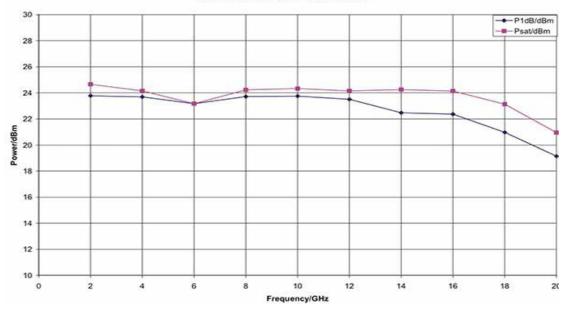
Die available upon request

Eclipse Microdevices EMD1705 is a GaAs MMIC PHEMPT Distributed general purpose driver amplifier. This MMIC is ideal for applications that requires a typical P1dB output power of +23 dBm up to 14 GHz, while requiring only 190mA from a + 8 Volt supply. Gain flatness of this device is less than 2.0 dB from DC to 20 GHz.The EMD1706 comes in a small RoHS compliant 4mm QFN leadless package and has excellent RF and thermal properties ideal for commercial and industrial applications.

Electrical Specifications @ +25°C, Vdd=8V, Ids=190mA

Parameters	Freq. (GHz)	Min.	Typical	Max.	Units
Gain	2.0 8.0 14.0 20.0		16.7 15.5 17.5 15.3		dB dB dB dB
Gain Flatness	DC to 10.0 GHz 10.0 to 20.0		±1.00 ±1.45	±1.40 ±1.80	dB dB
Gain Variation Over Temperature				0.02	dB/°C
Noise Figure			6.5		dB
Input Return Loss			10.0		dB
Output Return Loss			8.0		dB
1dB Compression Point	2.0 8.0 14.0 20.0		23.0 24.0 22.5 19.1		dBm dBm dBm
Saturated Output Power	2.0 8.0 14.0 20.0		25.0 24.6 24.2 21.0		dBm dBm dBm
3rd Order Intercept Point			28.0		dBm

1705 in Plastic - Power Performance



EMD1705QFN4 Driver Amplifier Module

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Absolute Maximum Rating

RF Input Power: +18 dBm Drain Voltage(Vdd): +8.0 VDC Gate Voltage(Vgg): -2 to 0 Volts Max Tj 85°C: +110°C

Storage Temp: -55 to +150°C

Operating Temp: -40 to +85°C

RECOMMENDED PCB LAYOUT 0 .032 [0.80] SQ .105 [2.68] INPUT 0 0 0 .022 [0.55]

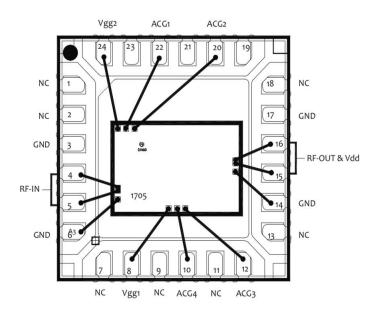
0

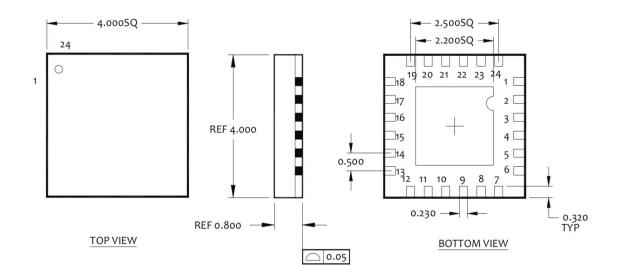
[0.30] PAD WIDTH

NOTES: 1. MATERIAL: ROGERS 4350, 10 MIL THICK 2, DIMENSIONS ARE IN INCHES[MM]

.010 GAP

Functional Block Diagram





About EclipseMDI

ECLIPSE Microdevices is located in San Jose, California. ECLIPSE has been developing high performance analog semiconductors for use in wireless radio frequency (RF), microwave, and millimeter wave for commercial and industrial applications. ECLIPSE has formed a strategic alliances - with foundries that features leading state-of-the-art process technologies and with manufacturing facilities for high-volume production of innovative RFIC's.